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DG2511, DG2512, DG2513

Vishay Siliconix

Low-Voltage, Low R_{ON} , Single Analog Switch In miniQFN-6 Package

DESCRIPTION

The DG2511, DG2512, DG2513 are low on-resistance, single-pole/double-throw or single-pole/single-throw monolithic CMOS analog switch. It is designed for low voltage applications. The DG2511, DG2512, DG2513 are ideal for portable and battery powered equipment, requiring high performance and efficient use of board space. In addition to the low on-resistance (1.3Ω at 2.7 V).

The DG2511 is an SPDT and the DG2512, DG2513 are SPST. The switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

The DG2511, DG2512, DG2513 are built on Vishay Siliconix's low voltage J15L process. An epitaxial layer prevents latchup.

Break-before-make is guaranteed.

The DG2511, DG2512, DG2513 represents a breakthrough in packaging development for analog switching products. The miniQFN-6 package (1.2 x 1 mm).

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations. For analog switching products manufactured with NiPdAu device terminations, the lead (Pb)-free "-E4" suffix is being used as a designator.

FEATURES

- Low voltage operation (1.8 V to 5.5 V)
- Low on-resistance - R_{ON} : 1.3Ω at 2.7 V
- Low charge injection
- Latch-up current > 300 mA (JESD78A)
- miniQFN-6 package (1.2 x 1 mm)
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

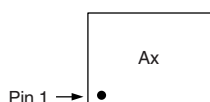
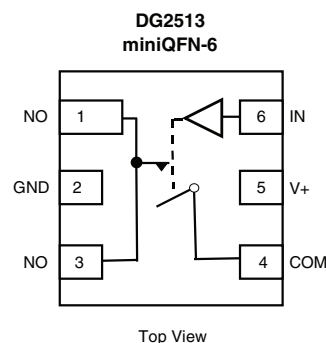
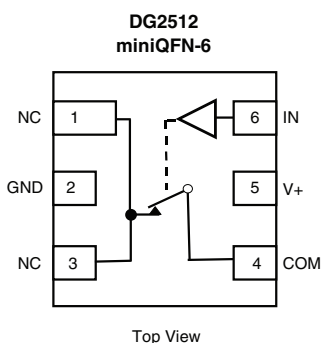
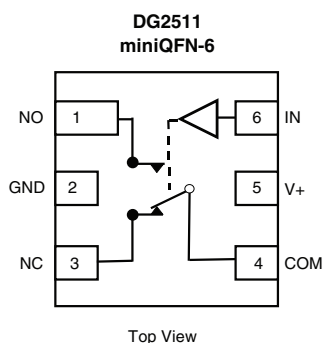
BENEFITS

- Reduced power consumption
- Simple logic interface
- High accuracy
- Reduce board space
- Guaranteed 2 V operation

APPLICATIONS

- Cellular phones
- Communication systems
- Portable test equipment
- Battery operated systems
- Sample and hold circuits
- ADC and DAC applications
- Low voltage data acquisition systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Device Marking: Ax for DG2511
Bx for DG2512
Cx for DG2513
x = Date/Lot Traceability Code
Note: Pin 1 has long lead

TRUTH TABLE

Logic	NC	NO
0	On	Off
1	Off	On

COMMERCIAL ORDERING INFORMATION

Temp Range	Package	Part Number
- 40 °C to 85 °C	miniQFN-6 Lead (Pb)-free with Tape and Reel	DG2511DN-T1-E4 DG2512DN-T1-E4 DG2513DN-T1-E4

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ABSOLUTE MAXIMUM RATINGS

Parameter	Limit	Unit
Reference V+ to GND	- 0.3 to + 6	V
IN, COM, NC, NO ^a	- 0.3 to (V+ + 0.3)	
Continuous Current (NO, NC, COM pins)	± 150	mA
Peak Current (Pulsed at 1 ms, 10 % duty cycle)	± 300	
Storage Temperature	D Suffix	°C
Power Dissipation (Packages) ^b	miniQFN-6 ^c	mW

Notes:

- a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
 b. All leads welded or soldered to PC board.
 c. Derate 2 mW/°C above 70 °C.

SPECIFICATIONS (V+ = 3 V)

Parameter	Symbol	Test Conditions Otherwise Unless Specified $V_+ = 3\text{ V}, \pm 10\%, V_{\text{IN}} = 0.4\text{ V}$ or 2 V^e	Temp. ^a	Limits - 40 °C to 85 °C			Unit
				Min. ^b	Typ. ^c	Max. ^b	
Analog Switch							
Analog Signal Range ^d	$V_{\text{NO}}, V_{\text{NC}}, V_{\text{COM}}$		Full	0		V_+	V
On-Resistance	R_{ON}	$V_+ = 2.7\text{ V}, V_{\text{COM}} = 0.5\text{ V}/1.5\text{ V}$ $I_{\text{NO}}, I_{\text{NC}} = 100\text{ mA}$	Room Full		1.4	1.7 1.9	Ω
R_{ON} Match	ΔR_{ON}		Room			0.15	
R_{ON} Flatness	R_{ON} Flatness		Room		0.3	0.4	
Switch Off Leakage Current ^f	$I_{\text{NO}}(\text{off})$ $I_{\text{NC}}(\text{off})$	$V_+ = 3.3\text{ V},$ $V_{\text{NO}}, V_{\text{NC}} = 1\text{ V}/3\text{ V}, V_{\text{COM}} = 3\text{ V}/1\text{ V}$	Room Full	- 2 - 20		2 20	nA
	$I_{\text{COM}}(\text{off})$		Room Full	- 2 - 20		2 20	
Channel-On Leakage Current ^f	$I_{\text{COM}}(\text{on})$	$V_+ = 3.3\text{ V}, V_{\text{NO}}, V_{\text{NC}} = V_{\text{COM}} = 1\text{ V}/3\text{ V}$	Room Full	- 2 - 20		2 20	
Digital Control							
Input High Voltage	V_{INH}		Full	1.6			V
Input Low Voltage	V_{INL}		Full			0.4	
Input Capacitance	C_{in}		Full		4		pF
Input Current	I_{INL} or I_{INH}	$V_{\text{IN}} = 0$ or V_+	Full	1		1	μA
Dynamic Characteristics							
Turn-On Time	t_{ON}	$V_+ = 2.7\text{ V}, V_{\text{NO}}$ or $V_{\text{NC}} = 1.5\text{ V},$ $R_{\text{L}} = 50\ \Omega, C_{\text{L}} = 35\text{ pF}$	Room Full		18	43 49	ns
Turn-Off Time	t_{OFF}		Room Full		7	32 34	
Break-Before-Make Time	t_{BBM}		Room	1	12		
Charge Injection ^d	Q_{INJ}	$C_{\text{L}} = 1\text{ nF}, V_{\text{GEN}} = 0\text{ V}, R_{\text{GEN}} = 0\ \Omega$	Room		3		pC
Off-Isolation ^d	OIRR	$R_{\text{L}} = 50\ \Omega, C_{\text{L}} = 5\text{ pF}, f = 1\text{ MHz}$	Room		- 58		dB
Crosstalk ^d	X_{TALK}		Room		- 64		
$N_{\text{O}}, N_{\text{C}}$ Off Capacitance ^d	$C_{\text{NO}}(\text{off})$ $C_{\text{NC}}(\text{off})$	$V_{\text{IN}} = 0$ or $V_+, f = 1\text{ MHz}$	Room		21		pF
Channel-On Capacitance ^d	C_{ON}		Room		61		
Power Supply							
Power Supply Range	V_+			1.8		5.5	V
Power Supply Current	I_+	$V_{\text{IN}} = 0$ or V_+			0.01	1	μA



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SPECIFICATIONS (V+ = 5 V)							
Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 5 V, ± 10 %, VIN = 0.6 V or 1.8 V ^e	Temp. ^a	Limits - 40 °C to 85 °C			Unit
				Min. ^b	Typ. ^c	Max. ^b	
Analog Switch							
Analog Signal Range ^d	VNO, VNC, VCOM		Full	0		V+	V
On-Resistance	RON	V+ = 4.5 V, VCOM = 0.5 V/2.5 V, INO, INC = 100 mA	Room Full		1	1.3 1.45	Ω
RON Match	ΔRON		Room			0.15	
RON Flatness	RON Flatness		Room		0.3	0.4	
Switch Off Leakage Current	INO(off) INC(off)	V+ = 5.5 V, VNO, VNC= 1 V/4.5 V, VCOM = 4.5 V/1 V	Room Full	- 2 - 20		2 20	nA
	ICOM(off)		Room Full	- 2 - 20		2 20	
	Channel-On Leakage Current		ICOM(on)	Room Full	- 2 - 20		
Digital Control							
Input High Voltage	VINH		Full	1.8			V
Input Low Voltage	VINL		Full			0.6	
Input Capacitance	Cin		Full		4		pF
Input Current	IINL or IINH	VIN = 0 or V+	Full	1		1	μA
Dynamic Characteristics							
Turn-On Time	tON	VNO or VNC = 2.5 V, RL = 50 Ω, CL = 35 pF	Room Full		11	35 39	ns
Turn-Off Time	tOFF		Room Full		6	31 33	
Break-Before-Make Time	tBBM		Room	1	5		
Charge Injection ^d	QINJ	CL = 1 nF, VGEN = 0 V, RGEN = 0 Ω	Room		14		pC
Off-Isolation ^d	OIRR	RL = 50 Ω, CL = 5 pF, f = 1 MHz	Room		- 58		dB
Crosstalk ^d	XTALK		Room		- 64		
NO, NC Off Capacitance ^d	CNO(off) CNC(off)	VIN = 0 or V+, f = 1 MHz	Room		19		pF
Channel-On Capacitance ^d	CON		Room		61		
Power Supply							
Power Supply Range	V+	VIN = 0 or V+		1.8		5.5	V
Power Supply Current	I+				0.01	1	μA

Notes:

- Room = 25 °C, Full = as determined by the operating suffix.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- Typical values are for design aid only, not guaranteed nor subject to production testing.
- Guarantee by design, nor subjected to production test.
- V_{IN} = input voltage to perform proper function.
- Guaranteed by 5 V leakage testing, not production tested.

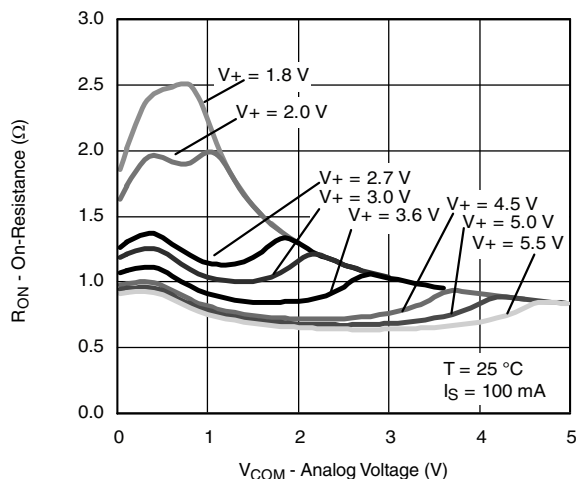
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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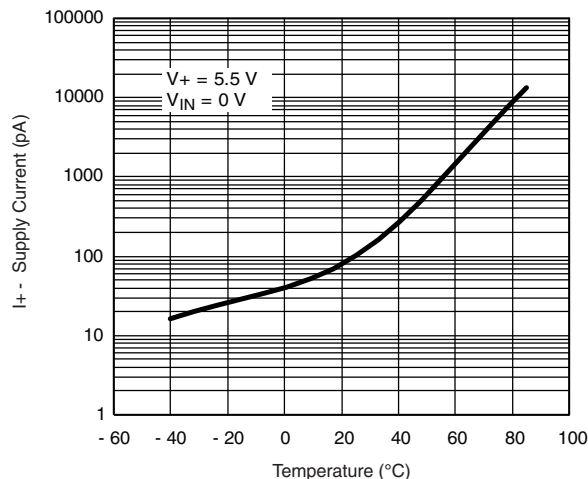
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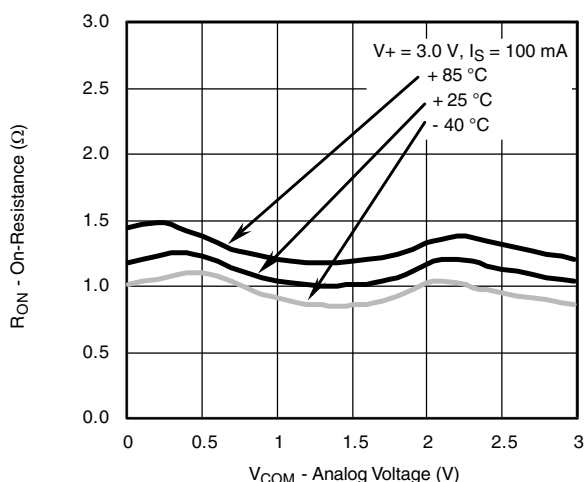
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



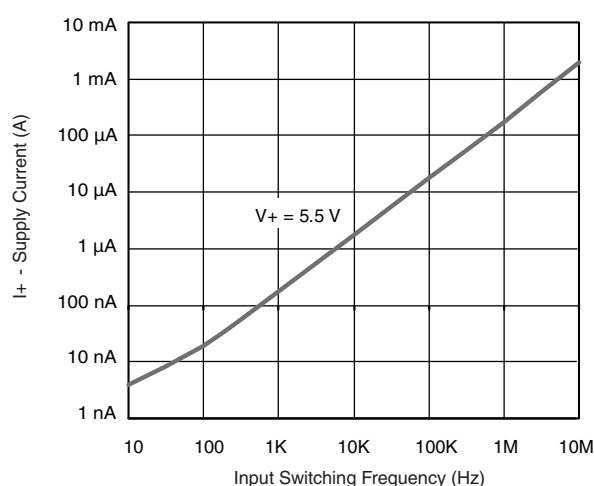
RON vs. VCOM and Supply Voltage



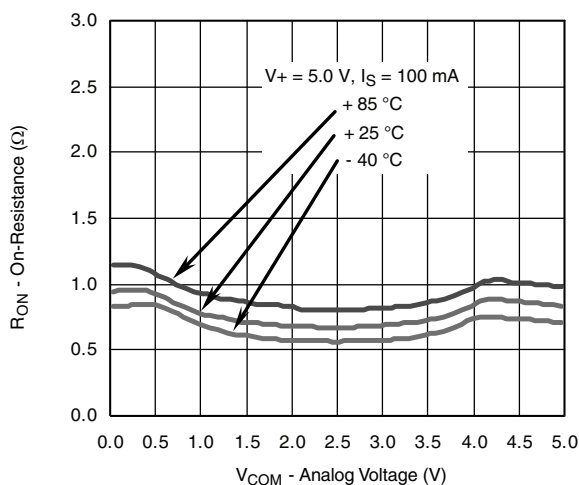
Supply Current vs. Temperature



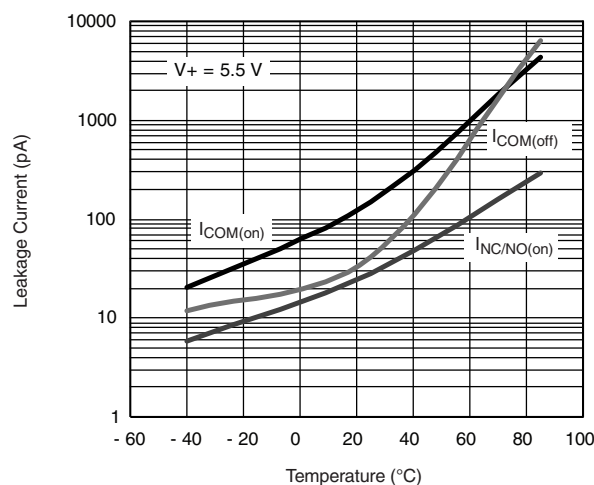
RON vs. Analog Voltage and Temperature



Supply Current vs. Input Switching Frequency



RON vs. Analog Voltage and Temperature



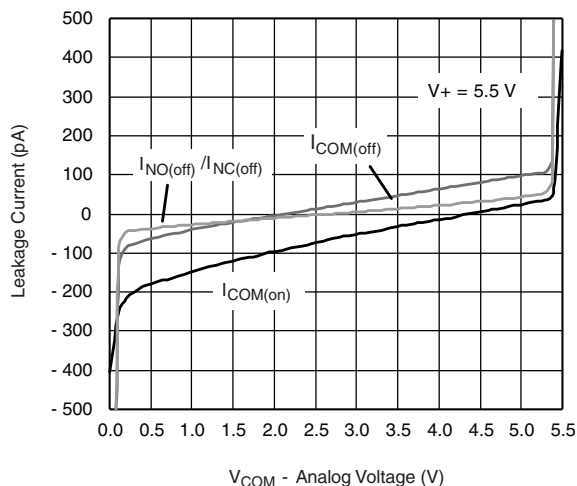
Leakage Current vs. Temperature



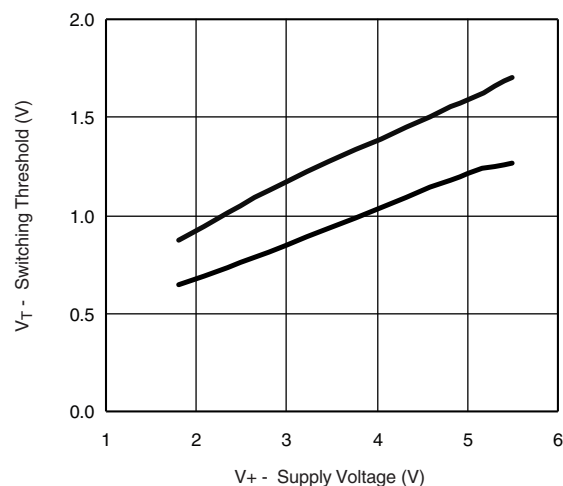
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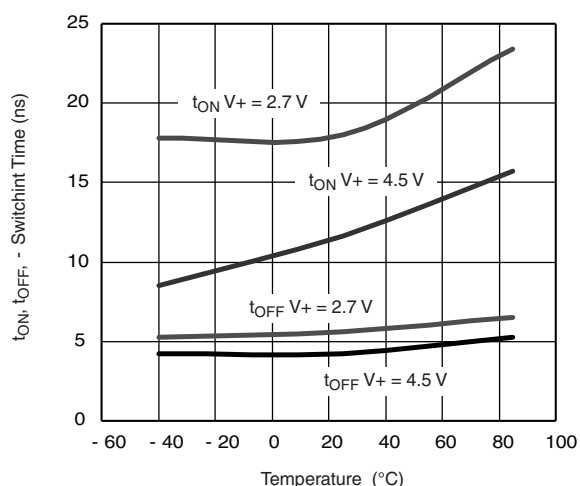
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



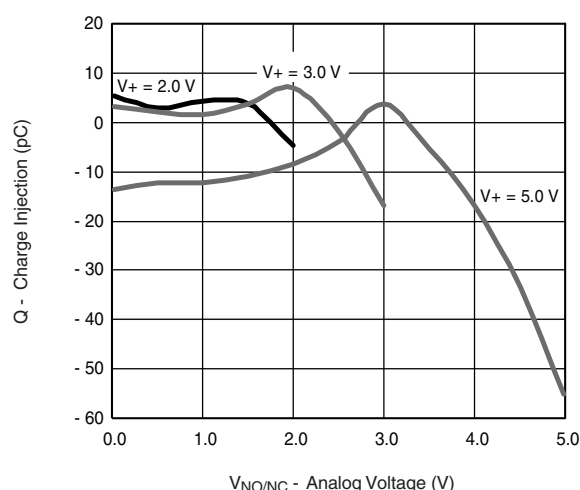
Leakage vs. Analog Voltage



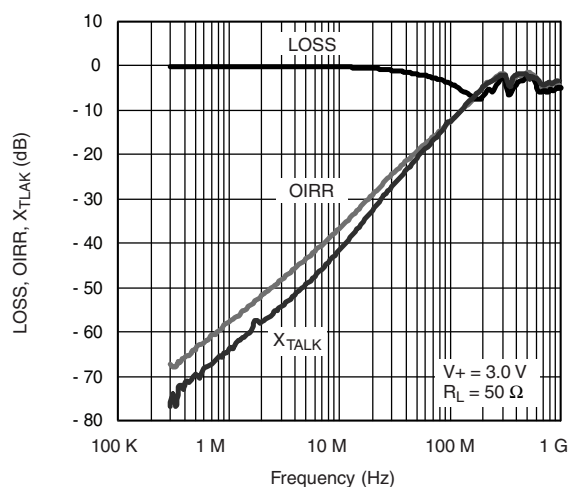
Switching Threshold vs. Supply Voltage



Switching Time vs. Temperature and Supply Voltage



Charge Injection vs. Analog Voltage



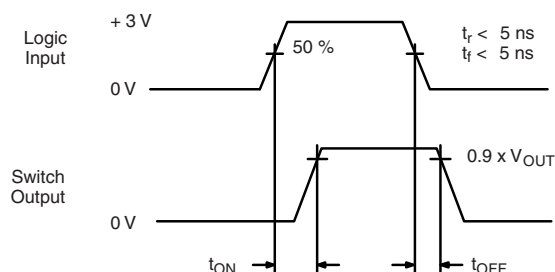
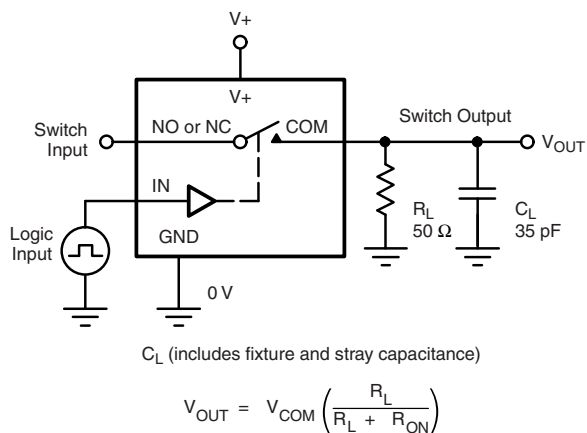
Insertion Loss, Off-Isolation, Crosstalk vs. Frequency

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TEST CIRCUITS



Logic "1" = Switch On
Logic input waveforms inverted for switches that have the opposite logic sense.

Figure 1. Switching Time

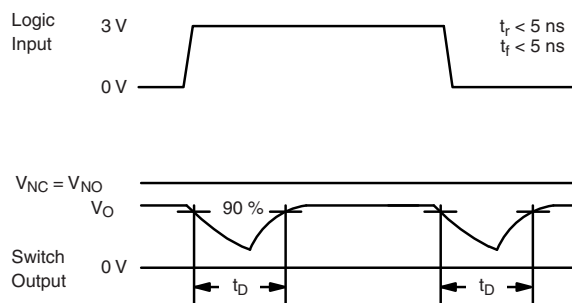
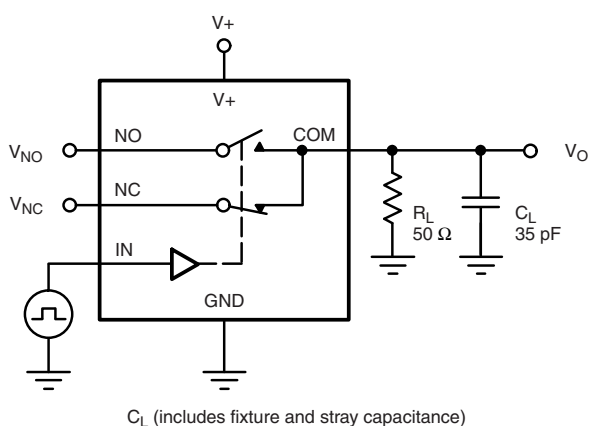
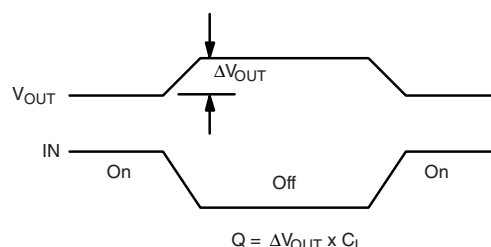
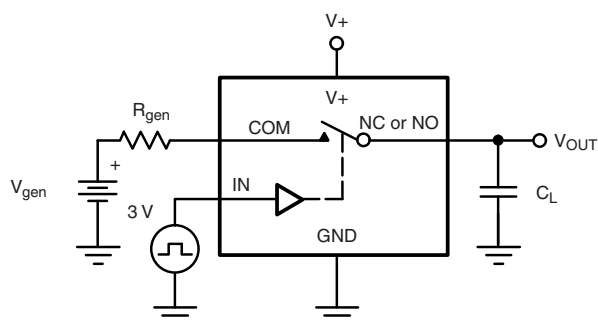


Figure 2. Break-Before-Make Interval



IN depends on switch configuration: input polarity determined by sense of switch.

Figure 3. Charge Injection



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TEST CIRCUITS

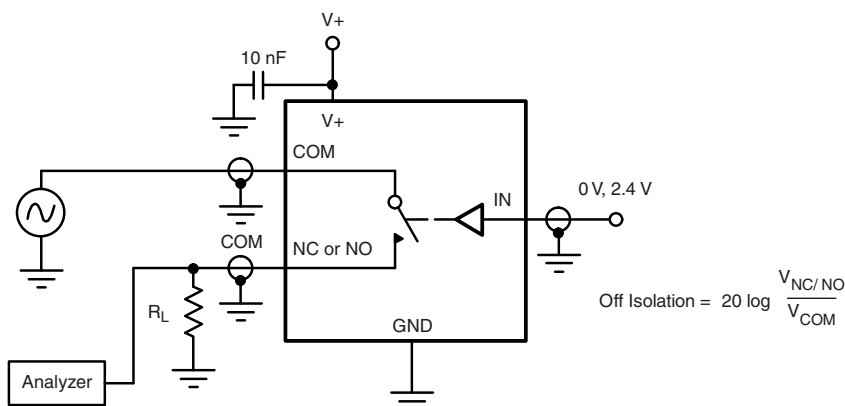


Figure 4. Off-Isolation

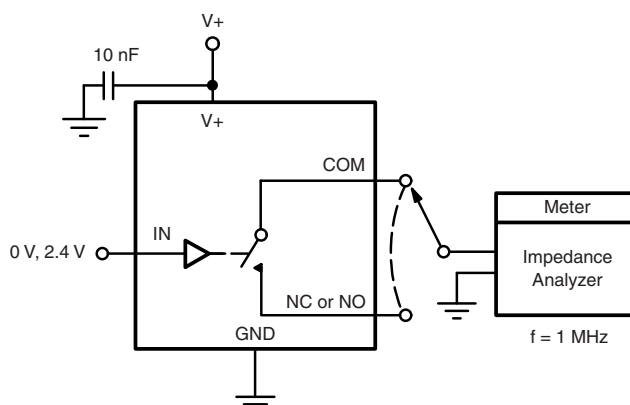


Figure 5. Channel Off/On Capacitance

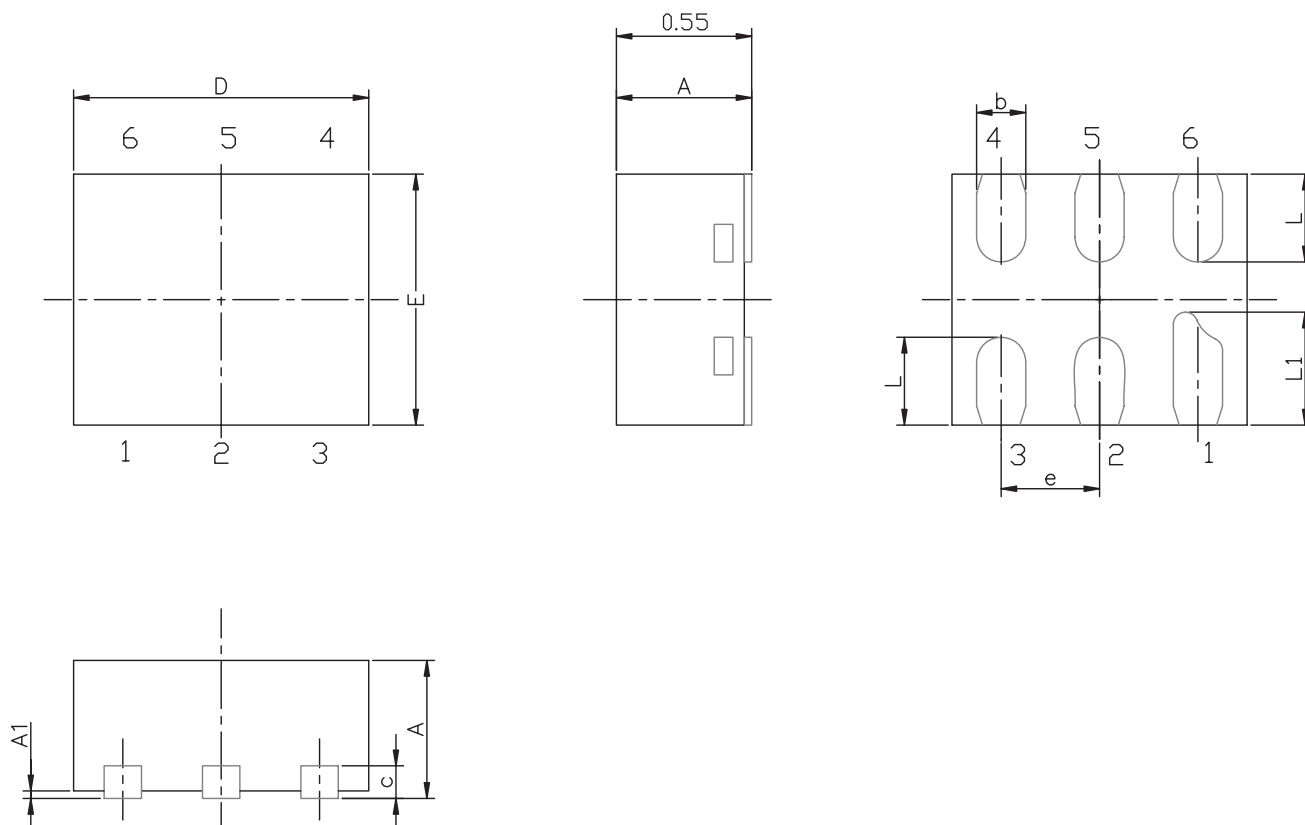
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Package Information

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MINI QFN-6L CASE OUTLINE



DIM	MILLIMETERS			INCHES		
	MIN.	NAM.	MAX.	MIN.	NAM.	MAX.
A	0.50	0.55	0.60	0.0197	0.0217	0.0236
A1	0.00	-	0.05	0.000	-	0.002
b	0.15	0.20	0.25	0.006	0.008	0.010
c	0.15 REF			0.006 REF		
D	1.15	1.20	1.25	0.045	0.047	0.049
E	0.95	1.00	1.05	0.037	0.039	0.041
e	0.40 BSC			0.016 BSC		
L	0.30	0.35	0.40	0.012	0.014	0.016
L1	0.40	0.45	0.50	0.016	0.018	0.020

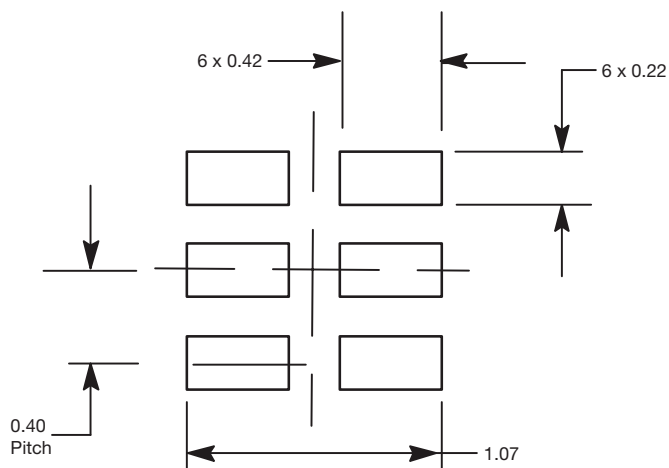
ECN T-07039-Rev. A, 12-Feb-07
DWG: 5958



PAD Pattern

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RECOMMENDED MINIMUM PADS FOR MINI QFN 6L



Mounting Footprint
Dimensions in mm



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